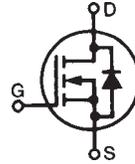
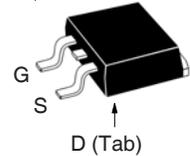
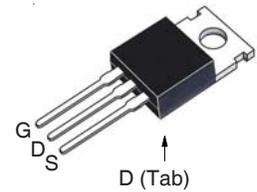


**Trench™ HiperFET™
Power MOSFET**
**IXFA130N10T
IXFP130N10T**
 $V_{DSS} = 100V$
 $I_{D25} = 130A$
 $R_{DS(on)} \leq 9.1m\Omega$

 N-Channel Enhancement Mode
 Avalanche Rated
 Fast Intrinsic Diode

**TO-263
(IXFA)**

**TO-220
(IXFP)**

 G = Gate D = Drain
 S = Source Tab = Drain

| Symbol | Test Conditions | Maximum Ratings | |
|---------------|---|--------------------|------------|
| V_{DSS} | $T_J = 25^\circ C$ to $175^\circ C$ | 100 | V |
| V_{DGR} | $T_J = 25^\circ C$ to $175^\circ C$, $R_{GS} = 1M\Omega$ | 100 | V |
| V_{GSS} | Continuous | ± 20 | V |
| V_{GSM} | Transient | ± 30 | V |
| I_{D25} | $T_C = 25^\circ C$ | 130 | A |
| I_{LRMS} | Lead Current Limit, RMS | 120 | A |
| I_{DM} | $T_C = 25^\circ C$, Pulse Width Limited by T_{JM} | 350 | A |
| I_A | $T_C = 25^\circ C$ | 65 | A |
| E_{AS} | $T_C = 25^\circ C$ | 750 | mJ |
| P_D | $T_C = 25^\circ C$ | 360 | W |
| T_J | | -55 ... +175 | $^\circ C$ |
| T_{JM} | | 175 | $^\circ C$ |
| T_{stg} | | -55 ... +175 | $^\circ C$ |
| T_L | Maximum Lead Temperature for Soldering | 300 | $^\circ C$ |
| T_{SOLD} | 1.6 mm (0.062in.) from Case for 10s | 260 | $^\circ C$ |
| F_C | Mounting Force (TO-263) | 10..65 / 2.2..14.6 | N/lb |
| M_d | Mounting Torque (TO-220) | 1.13 / 10 | Nm/lb.in |
| Weight | TO-263 | 2.5 | g |
| | TO-220 | 3.0 | g |

Features

- Ultra-Low On Resistance
- Avalanche Rated
- Low Package Inductance
 - Easy to Drive and to Protect
- $175^\circ C$ Operating Temperature
- Fast Intrinsic Diode

Advantages

- Easy to Mount
- Space Savings
- High Power Density

Applications

- Automotive
 - Motor Drives
 - 42V Power Bus
 - ABS Systems
- DC/DC Converters and Off-line UPS
- Primary Switch for 24V and 48V Systems
- Distributed Power Architectures and VRMs
- Electronic Valve Train Systems
- High Current Switching Applications
- High Voltage Synchronous Rectifier

| Symbol | Test Conditions ($T_J = 25^\circ C$ Unless Otherwise Specified) | Characteristic Values | | |
|--------------|---|-----------------------|-----------|--------------------|
| | | Min. | Typ. | Max. |
| BV_{DSS} | $V_{GS} = 0V$, $I_D = 250\mu A$ | 100 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 1mA$ | 2.5 | | V |
| I_{GSS} | $V_{GS} = \pm 20V$, $V_{DS} = 0V$ | | ± 200 | nA |
| I_{DSS} | $V_{DS} = V_{DSS}$, $V_{GS} = 0V$ $T_J = 150^\circ C$ | | 10 500 | μA μA |
| $R_{DS(on)}$ | $V_{GS} = 10V$, $I_D = 25A$, Notes 1, 2 | | 9.1 | m Ω |

| Symbol | Test Conditions | Characteristic Values | | | | |
|---|---|-----------------------|------|--------------------|--------------------|----|
| | | Min. | Typ. | Max. | | |
| $(T_J = 25^\circ\text{C Unless Otherwise Specified})$ | | | | | | |
| g_{fs} | $V_{DS} = 10\text{V}, I_D = 60\text{A}, \text{Note 1}$ | 55 | 93 | S | | |
| C_{iss} | $V_{GS} = 0\text{V}, V_{DS} = 25\text{V}, f = 1\text{MHz}$ | | 5080 | pF | | |
| C_{oss} | | | | | 630 | pF |
| C_{rss} | | | | | 95 | pF |
| $t_{d(on)}$ | Resistive Switching Times $V_{GS} = 10\text{V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 25\text{A}$ $R_G = 5\Omega \text{ (External)}$ | | 30 | ns | | |
| t_r | | | | | 47 | ns |
| $t_{d(off)}$ | | | | | 44 | ns |
| t_f | | | | | 28 | ns |
| $Q_{g(on)}$ | $V_{GS} = 10\text{V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 25\text{A}$ | | 104 | nC | | |
| Q_{gs} | | | | | 30 | nC |
| Q_{gd} | | | | | 29 | nC |
| R_{thJC} | TO-220 | | 0.50 | 0.42 | $^\circ\text{C/W}$ | |
| R_{thCH} | | | | $^\circ\text{C/W}$ | | |

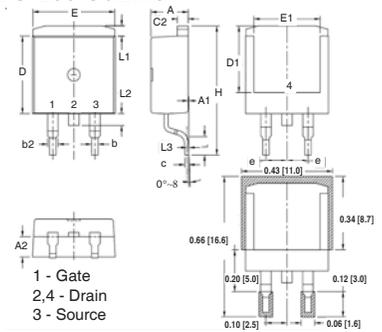
Source-Drain Diode

| Symbol | Test Conditions | Characteristic Values | | | |
|---|---|-----------------------|------|------|-----|
| | | Min. | Typ. | Max. | |
| $(T_J = 25^\circ\text{C Unless Otherwise Specified})$ | | | | | |
| I_S | $V_{GS} = 0\text{V}$ | | | 130 | A |
| I_{SM} | Repetitive, Pulse Width Limited by T_{JM} | | | 350 | A |
| V_{SD} | $I_F = 25\text{A}, V_{GS} = 0\text{V}, \text{Note 1}$ | | | 1.0 | V |
| t_{rr} | $I_F = 65\text{A}, -di/dt = 100\text{A}/\mu\text{s}$ $V_R = 0.5 \cdot V_{DSS}, V_{GS} = 0\text{V}$ | | 67 | ns | |
| I_{RM} | | | | | 4.7 |
| Q_{rr} | | | 160 | nC | |

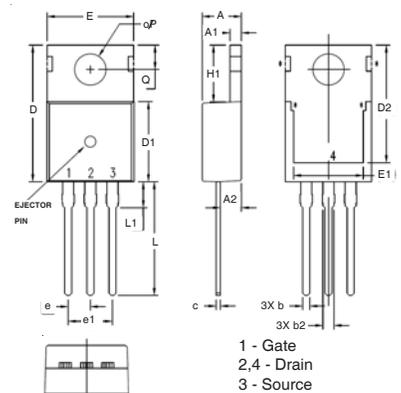
- Notes: 1. Pulse test, $t \leq 300 \mu\text{s}$; duty cycle, $d \leq 2\%$.
 2. On through-hole packages, $R_{DS(on)}$ Kelvin test contact location must be 5 mm or less from the package body.

PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

TO-263 Outline


| SYM | INCHES | | MILLIMETER | |
|------|----------|------|------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .170 | .185 | 4.30 | 4.70 |
| A1 | .000 | .008 | 0.00 | 0.20 |
| A2 | .091 | .098 | 2.30 | 2.50 |
| b | .028 | .035 | 0.70 | 0.90 |
| b2 | .046 | .060 | 1.18 | 1.52 |
| C | .018 | .024 | 0.45 | 0.60 |
| C2 | .049 | .060 | 1.25 | 1.52 |
| D | .340 | .370 | 8.63 | 9.40 |
| D1 | .300 | .327 | 7.62 | 8.30 |
| E | .380 | .410 | 9.65 | 10.41 |
| E1 | .270 | .330 | 6.86 | 8.38 |
| (e) | .100 BSC | | 2.54 BSC | |
| H | .580 | .620 | 14.73 | 15.75 |
| L | .075 | .105 | 1.91 | 2.67 |
| L1 | .039 | .060 | 1.00 | 1.52 |
| L2 | — | .070 | — | 1.77 |
| (L3) | .010 BSC | | 0.254 BSC | |

TO-220 Outline


| SYM | INCHES | | MILLIMETERS | |
|------|----------|------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .169 | .185 | 4.30 | 4.70 |
| A1 | .047 | .055 | 1.20 | 1.40 |
| A2 | .079 | .106 | 2.00 | 2.70 |
| b | .024 | .039 | 0.60 | 1.00 |
| b2 | .045 | .057 | 1.15 | 1.45 |
| c | .014 | .026 | 0.35 | 0.65 |
| D | .587 | .626 | 14.90 | 15.90 |
| D1 | .335 | .370 | 8.50 | 9.40 |
| (D2) | .500 | .531 | 12.70 | 13.50 |
| E | .382 | .406 | 9.70 | 10.30 |
| (E1) | .283 | .323 | 7.20 | 8.20 |
| e | .100 BSC | | 2.54 BSC | |
| e1 | .200 BSC | | 5.08 BSC | |
| H1 | .244 | .268 | 6.20 | 6.80 |
| L | .492 | .547 | 12.50 | 13.90 |
| L1 | .110 | .154 | 2.80 | 3.90 |
| ∅P | .134 | .150 | 3.40 | 3.80 |
| Q | .106 | .126 | 2.70 | 3.20 |

IXYS reserves the right to change limits, test conditions, and dimensions.

| | | | | | | | | | | |
|--|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665 | 6,404,065 B1 | 6,683,344 | 6,727,585 | 7,005,734 B2 | 7,157,338B2 |
| | 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343 | 6,710,405 B2 | 6,759,692 | 7,063,975 B2 | |
| | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505 | 6,710,463 | 6,771,478 B2 | 7,071,537 | |

Fig. 1. Output Characteristics @ $T_J = 25^\circ\text{C}$

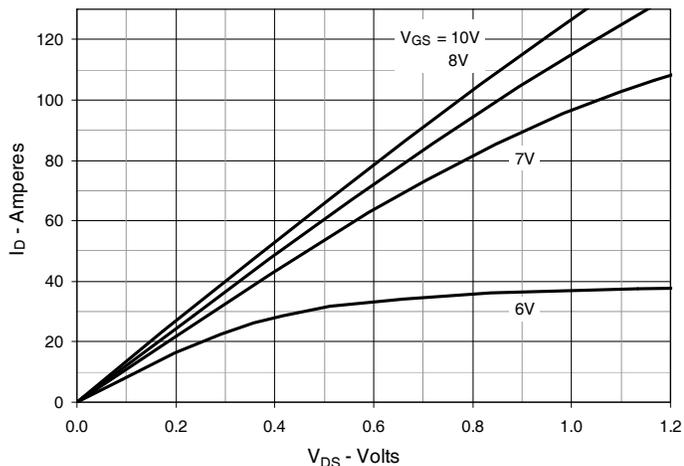


Fig. 2. Extended Output Characteristics @ $T_J = 25^\circ\text{C}$

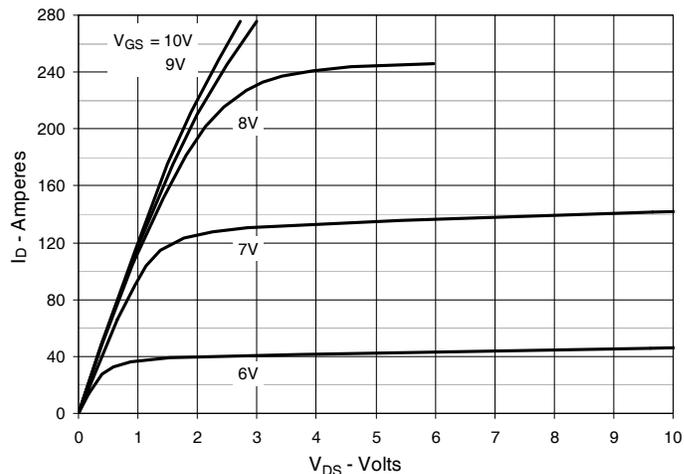


Fig. 3. Output Characteristics @ $T_J = 150^\circ\text{C}$

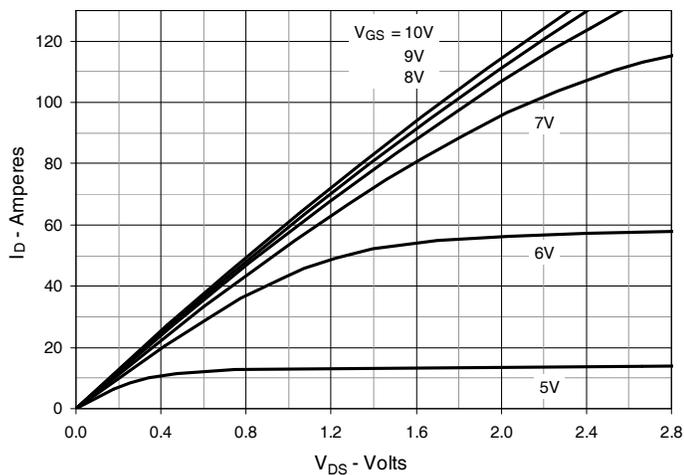


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 65\text{A}$ Value vs. Junction Temperature

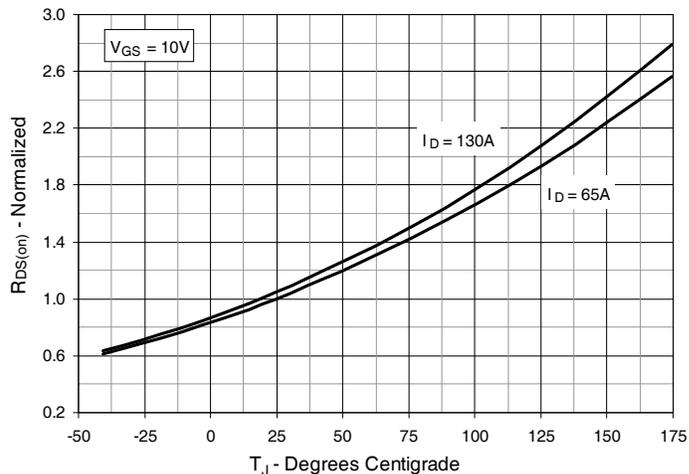


Fig. 5. $R_{DS(on)}$ Normalized to $I_D = 65\text{A}$ Value vs. Drain Current

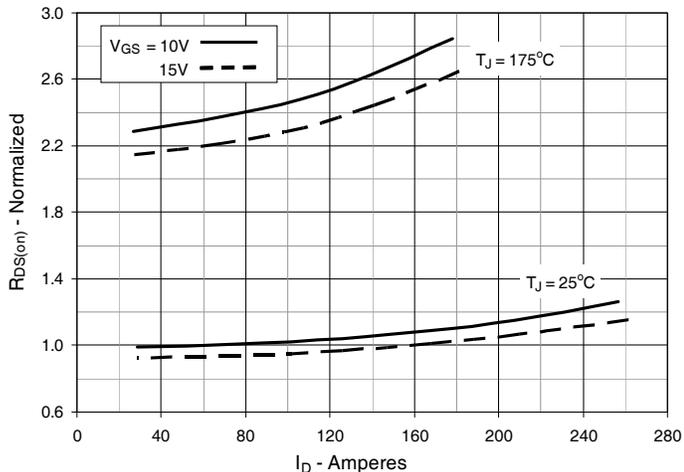


Fig. 6. Drain Current vs. Case Temperature

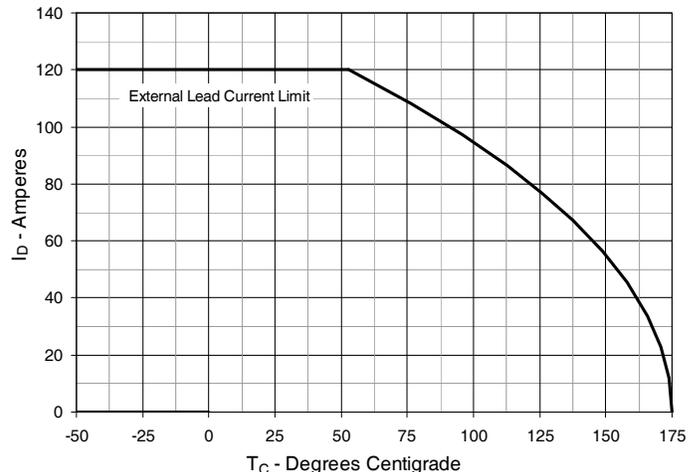


Fig. 7. Input Admittance

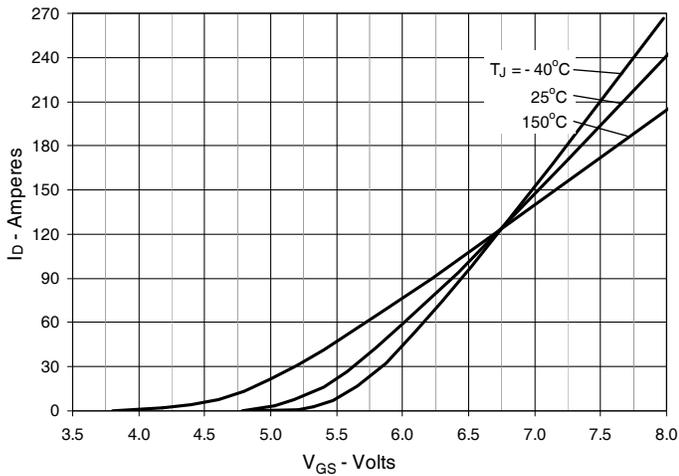


Fig. 8. Transconductance

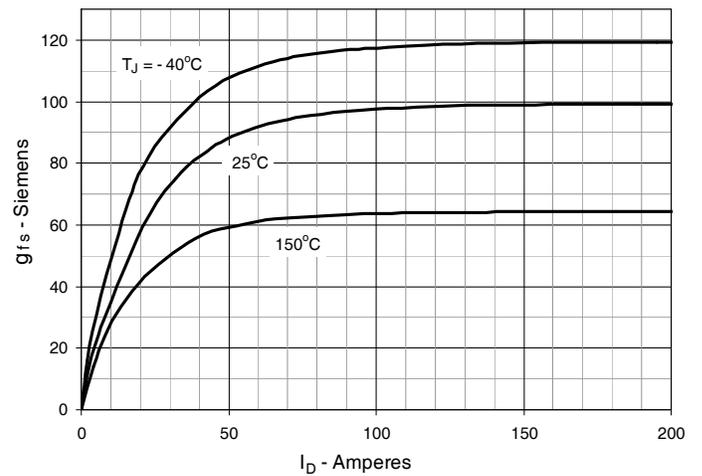


Fig. 9. Forward Voltage Drop of Intrinsic Diode

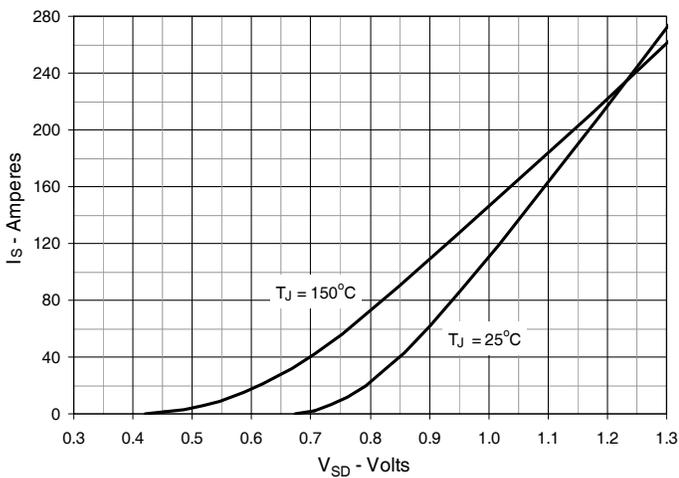


Fig. 10. Gate Charge

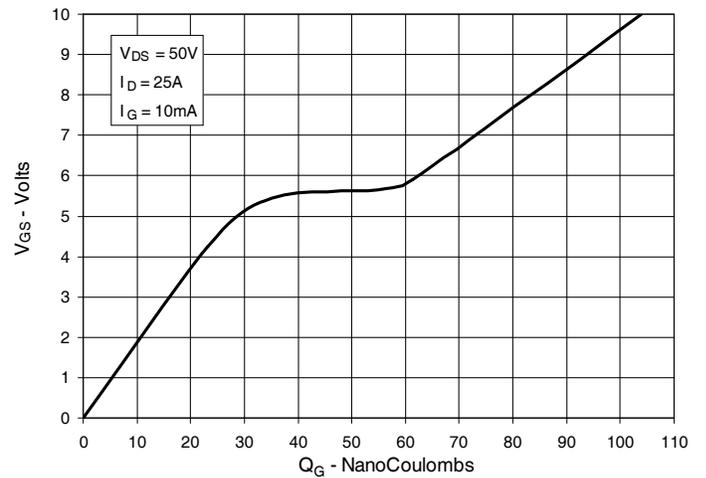


Fig. 11. Capacitance

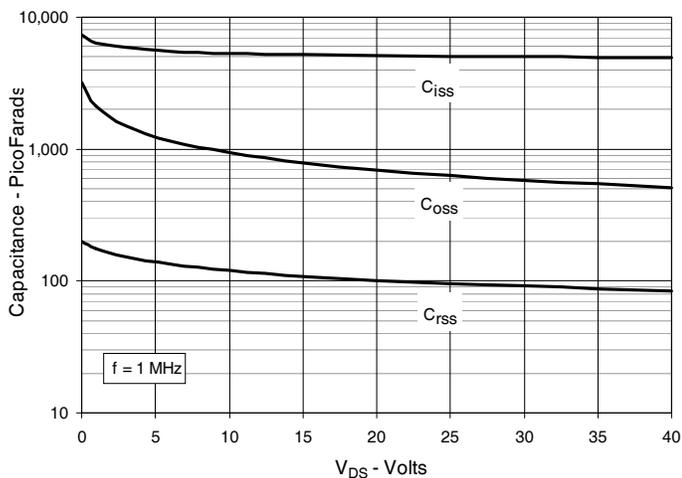


Fig. 12. Maximum Transient Thermal Impedance

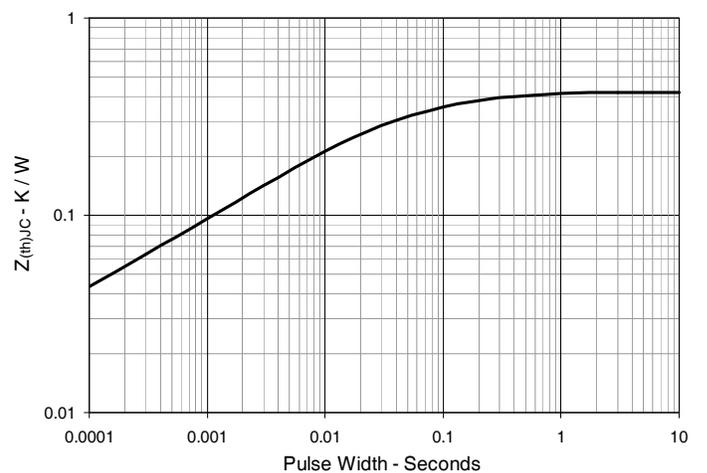


Fig. 13. Resistive Turn-on
Rise Time vs. Junction Temperature

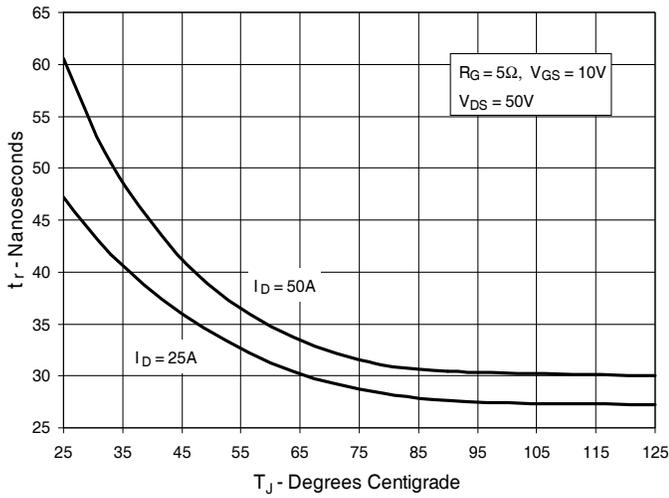


Fig. 14. Resistive Turn-on
Rise Time vs. Drain Current

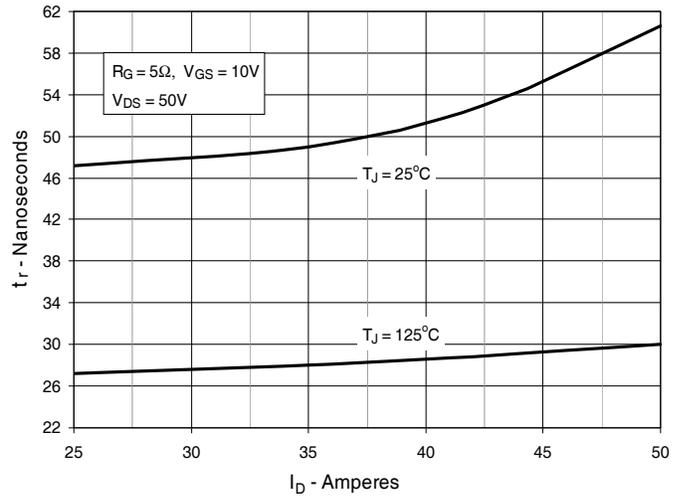


Fig. 15. Resistive Turn-on
Switching Times vs. Gate Resistance

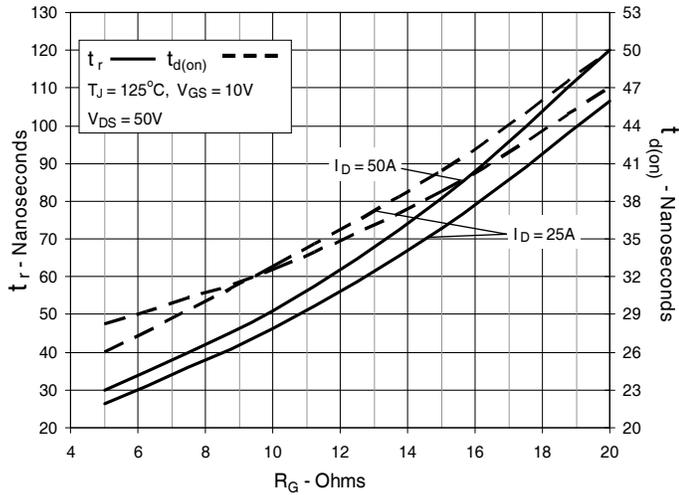


Fig. 16. Resistive Turn-off
Switching Times vs. Junction Temperature

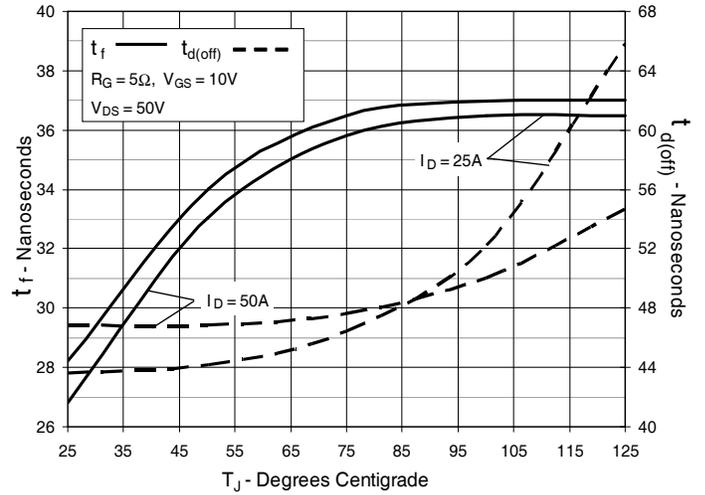


Fig. 17. Resistive Turn-off
Switching Times vs. Drain Current

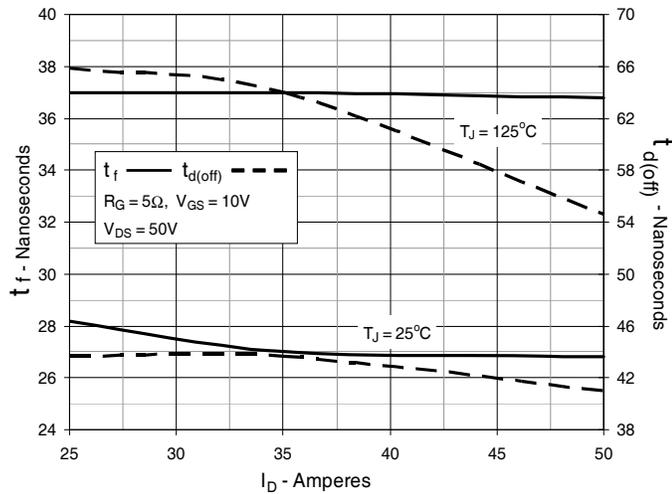
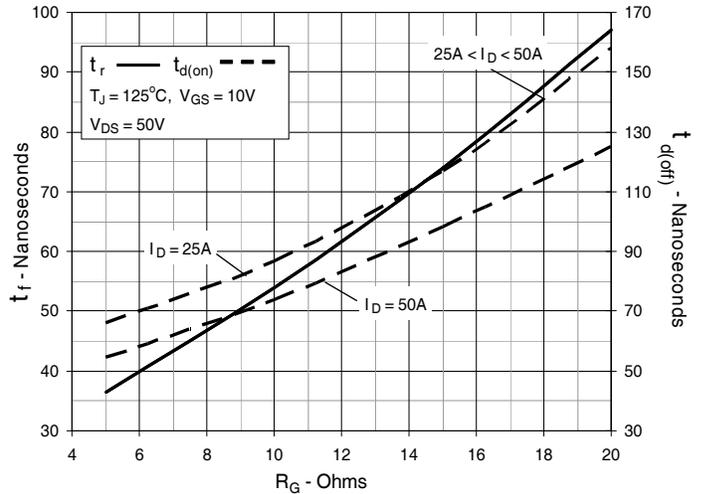


Fig. 18. Resistive Turn-off
Switching Times vs. Gate Resistance





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